

RD74LVC245B

Octal Bidirectional Transceivers with 3-state Outputs

REJ03D0386-0100

Rev.1.00

Aug. 26, 2004

Description

The RD74LVC245B has eight buffers with three state outputs in a 20 pin package. When (DIR) is high, data flows from the A inputs to the B outputs, and when (DIR) is low, data flows from the B inputs to the A outputs. A and B bus are separated by making enable input (\overline{OE}) high level. Low voltage and high-speed operation is suitable at the battery drive product (note type personal computer) and low power consumption extends the life of a battery for long time operation.

Features

- $V_{CC} = 1.65 \text{ V to } 5.5 \text{ V}$
- All inputs $V_{IH} (\text{Max.}) = 5.5 \text{ V } (@V_{CC} = 0 \text{ V to } 5.5 \text{ V})$
- All input outputs $V_{IO} (\text{Max.}) = 5.5 \text{ V } (@V_{CC} = 0 \text{ V or output off state})$
- Typical V_{OL} ground bounce $< 0.8 \text{ V } (@V_{CC} = 3.3 \text{ V, } T_a = 25^\circ\text{C})$
- Typical V_{OH} undershoot $> 2.0 \text{ V } (@V_{CC} = 3.3 \text{ V, } T_a = 25^\circ\text{C})$
- High output current
 - $\pm 4 \text{ mA } (@V_{CC} = 1.65 \text{ V})$
 - $\pm 8 \text{ mA } (@V_{CC} = 2.3 \text{ V})$
 - $\pm 12 \text{ mA } (@V_{CC} = 2.7 \text{ V})$
 - $\pm 24 \text{ mA } (@V_{CC} = 3.0 \text{ V to } 5.5 \text{ V})$
- Ordering Information

Part Name	Package Type	Package Code	Package Abbreviation	Taping Abbreviation (Quantity)
RD74LVC245BFPEL	SOP-20 pin (JEITA)	FP-20DAV	FP	EL (2,000 pcs/reel)
RD74LVC245BTELL	TSSOP-20 pin	TTP-20DAV	T	ELL (2,000 pcs/reel)

Function Table

Inputs		Operation
\overline{OE}	DIR	
L	L	B data to A bus
L	H	A data to B bus
H	X	Z

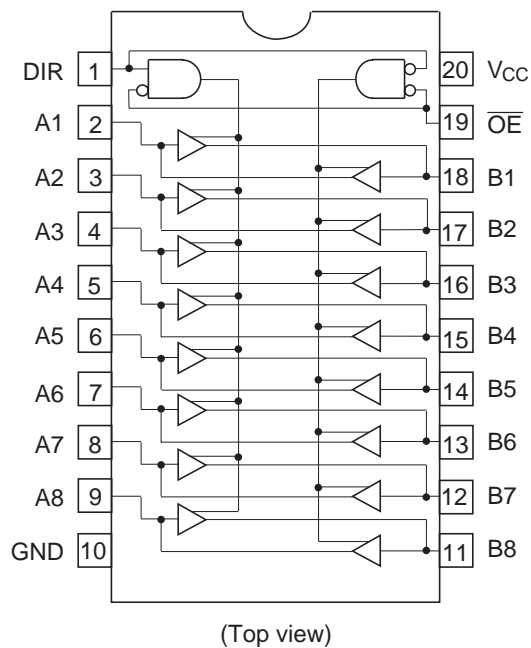
H: High level

L: Low level

X: Immaterial

Z: High impedance

Pin Arrangement



Absolute Maximum Ratings

Item	Symbol	Ratings	Unit	Conditions
Supply voltage	V_{CC}	-0.5 to 7.0	V	
Input diode current	I_{IK}	-50	mA	$V_I = -0.5$ V
Input voltage	V_I	-0.5 to 7.0	V	
Output diode current	I_{OK}	-50	mA	$V_O = -0.5$ V
		50		$V_O = V_{CC} + 0.5$ V
Input / output voltage	$V_{I/O}$	-0.5 to $V_{CC} + 0.5$	V	Output "H" or "L"
		-0.5 to 7.0		Output "Z" or V_{CC} :OFF
Output current	I_O	± 50	mA	
V_{CC} , GND current / pin	I_{CC} or I_{GND}	100	mA	
Storage temperature	T_{stg}	-65 to 150	$^{\circ}\text{C}$	

Note: The absolute maximum ratings are values, which must not individually be exceeded, and furthermore, no two of which may be realized at the same time.

Recommended Operating Conditions

Item	Symbol	Ratings	Unit	Conditions
Supply voltage	V_{CC}	1.5 to 5.5	V	Data hold
		1.65 to 5.5		At operation
Input / output voltage	V_I	0 to 5.5	V	
	V_O	0 to V_{CC}		Output "H" or "L"
		0 to 5.5		Output "Z" or V_{CC} : OFF
Operating temperature	T_a	-40 to 85	°C	
Output current	I_{OH}	-4	mA	$V_{CC} = 1.65\text{ V}$
		-8		$V_{CC} = 2.3\text{ V}$
		-12		$V_{CC} = 2.7\text{ V}$
		-24		$V_{CC} = 3.0\text{ V to }5.5\text{ V}$
	I_{OL}	4	mA	$V_{CC} = 1.65\text{ V}$
		8		$V_{CC} = 2.3\text{ V}$
		12		$V_{CC} = 2.7\text{ V}$
		24		$V_{CC} = 3.0\text{ V to }5.5\text{ V}$
Input rise / fall time ^{*1}	t_r, t_f	20	ns/V	$V_{CC} = 1.65\text{ V to }2.7\text{ V}$
		10		$V_{CC} = 3.0\text{ V to }5.5\text{ V}$

Notes: 1. This item guarantees maximum limit when one input switches.

Waveform: Refer to test circuit of switching characteristics.

Electrical Characteristics

Item	Symbol	V _{CC} (V)	Ta = −40 to 85°C		Unit	Test Conditions
			Min	Max		
Input voltage	V _{IH}	1.65 to 1.95	V _{CC} ×0.65	—	V	
		2.3 to 2.7	1.7	—		
		2.7 to 3.6	2.0	—		
		4.5 to 5.5	V _{CC} ×0.7	—		
	V _{IL}	1.65 to 1.95	—	V _{CC} ×0.35	V	
		2.3 to 2.7	—	0.7		
		2.7 to 3.6	—	0.8		
		4.5 to 5.5	—	V _{CC} ×0.3		
Output voltage	V _{OH}	1.65 to 5.5	V _{CC} −0.2	—	V	I _{OH} = −100 μA
		1.65	1.2	—		I _{OH} = −4 mA
		2.3	1.7	—		I _{OH} = −8 mA
		2.7	2.2	—		I _{OH} = −12 mA
		3.0	2.4	—		
		3.0	2.2	—		I _{OH} = −24 mA
		4.5	3.8	—		
	V _{OL}	1.65 to 5.5	—	0.2	V	I _{OL} = 100 μA
		1.65	—	0.45		I _{OL} = 4 mA
		2.3	—	0.7		I _{OL} = 8 mA
		2.7	—	0.4		I _{OL} = 12 mA
		3.0	—	0.55		I _{OL} = 24 mA
		4.5	—	0.55		
Input current	I _{IN}	0 to 5.5	—	±5.0	μA	V _{IN} = 5.5 V or GND
Output leak current	I _{OFF}	0	—	±5.0	μA	V _{IN} / V _{OUT} = 5.5 V
Off state output current	I _{OZ}	2.7 to 5.5	—	±5.0	μA	V _{IN} = V _{CC} , GND, V _{OUT} = 5.5 V or GND
Quiescent supply current	I _{CC}	2.7 to 3.6	—	±5.0	μA	V _{IN} = 3.6 to 5.5 V
		2.7 to 5.5	—	5.0		V _{IN} = V _{CC} or GND
	ΔI _{CC}	2.7 to 3.6	—	500	μA	V _{IN} = one input at (V _{CC} −0.6)V, other inputs at V _{CC} or GND

Switching Characteristics

Item	Symbol	V _{CC} (V)	Ta = -40 to 85°C			Unit	From (Input)	To (Output)
			Min	Typ	Max			
Propagation delay time	t _{PLH}	1.8±0.15	1.0	—	12.7	ns	A or B	B or A
	t _{PHL}	2.5±0.2	1.0	—	8.3			
		2.7	1.0	—	7.3			
		3.3±0.3	1.5	—	6.3			
		5.0±0.5	1.0	—	4.8			
Output enable time	t _{ZH}	1.8±0.15	1.0	—	15.3	ns	OE	A or B
	t _{ZL}	2.5±0.2	1.0	—	10.5			
		2.7	1.0	—	9.5			
		3.3±0.3	1.5	—	8.5			
		5.0±0.5	1.0	—	7.0			
Output disable time	t _{ZH}	1.8±0.15	1.0	—	17.0	ns	OE	A or B
	t _{LZ}	2.5±0.2	1.0	—	9.5			
		2.7	1.0	—	8.5			
		3.3±0.3	1.7	—	7.5			
		5.0±0.5	1.0	—	6.5			
Between output pins skew *1	t _{OSLH}	1.8±0.15	—	—	—	ns		
	t _{OSHL}	2.5±0.2	—	—	—			
		2.7	—	—	—			
		3.3±0.3	—	—	1.0			
		5.0±0.5	—	—	1.0			
Input capacitance	C _{IN}	3.3	—	4.0	—	pF		
Output capacitance	C _O	3.3	—	8.0	—	pF		

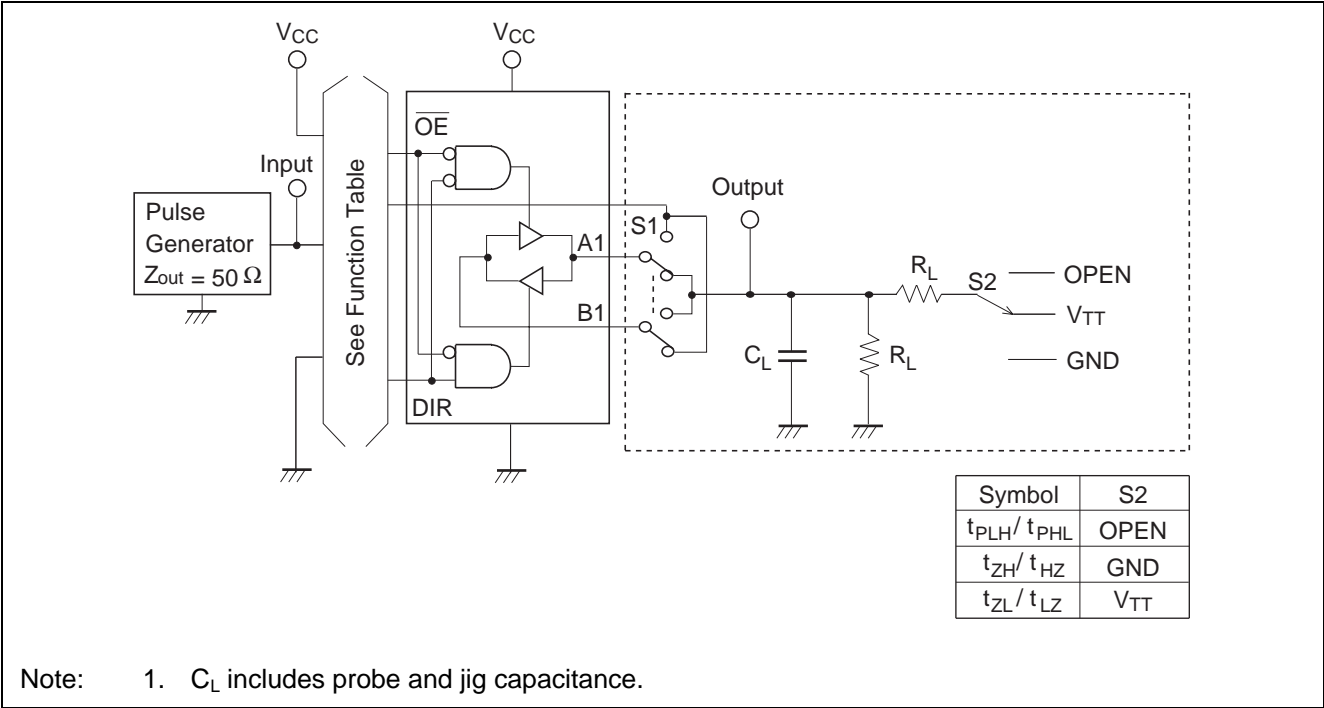
Note: 1. This parameter is characterized but not tested.

$$t_{OSLH} = |t_{PLHm} - t_{PLHn}|, t_{OSHL} = |t_{PHLm} - t_{PHLn}|$$

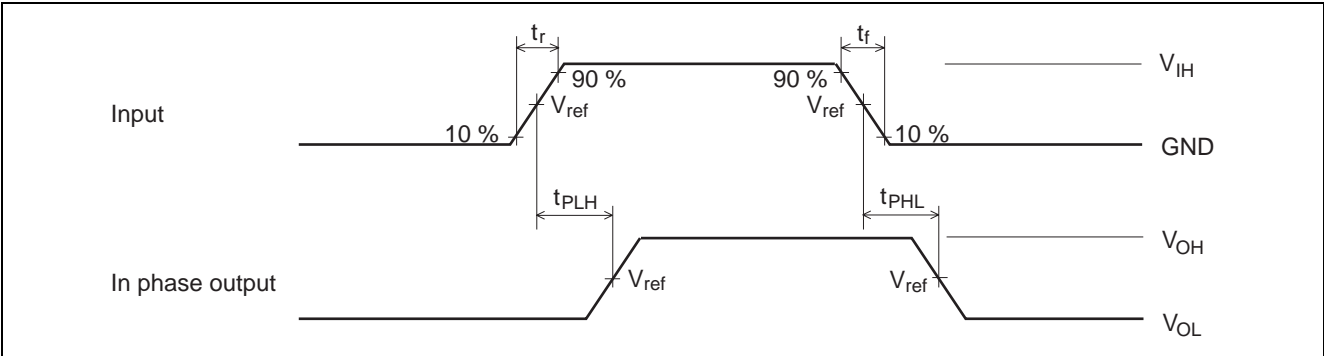
Operating Characteristics

Item	Symbol	V _{CC} (V)	Ta = 25°C			Unit	Test Conditions
			Min	Typ	Max		
Power dissipation capacitance	C _{PD}	1.8	—	42	—	pF	f = 10 MHz
		2.5	—	43	—		
		3.3	—	45	—		
		5.0	—	47	—		

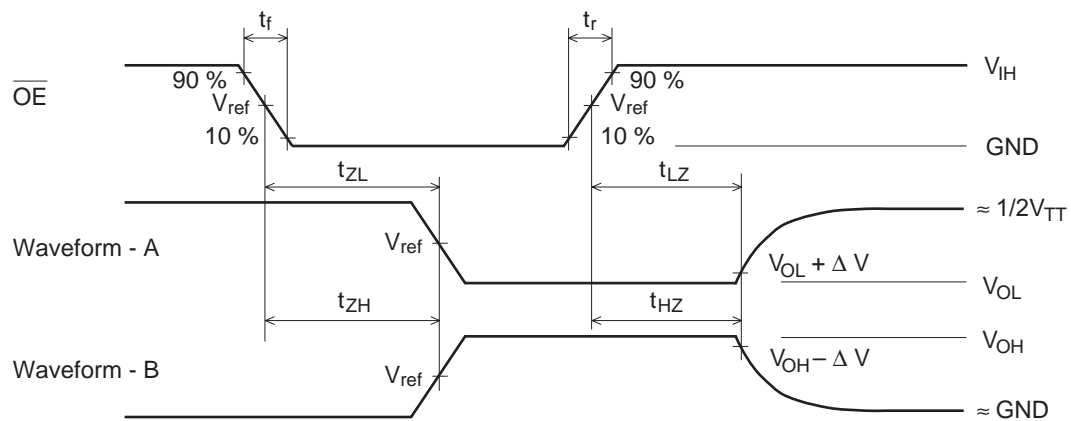
Test Circuit



Waveforms – 1



Waveforms – 2

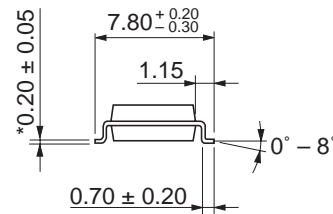
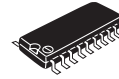
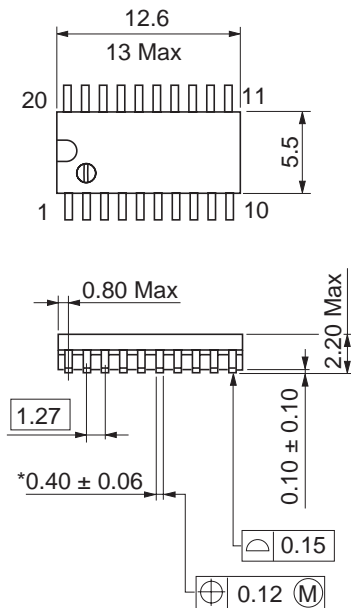


V _{CC} (V)	INPUTS		V _{ref}	V _{TT}	C _L	R _L	ΔV
	V _I	t _r /t _f					
V _{CC} = 1.8±0.15 V	V _{CC}	≤ 2 ns	1/2 V _{CC}	2× V _{CC}	30 pF	1.0 kΩ	0.15 V
V _{CC} = 2.5±0.2 V	V _{CC}	≤ 2 ns	1/2 V _{CC}	2× V _{CC}	30 pF	500 Ω	0.15 V
V _{CC} = 2.7 V	2.7 V	≤ 2.5 ns	1.5 V	6 V	50 pF	500 Ω	0.3 V
V _{CC} = 3.3±0.3 V	2.7 V	≤ 2.5 ns	1.5 V	6 V	50 pF	500 Ω	0.3 V
V _{CC} = 5.0±0.5 V	V _{CC}	≤ 2.5 ns	1/2 V _{CC}	2× V _{CC}	50 pF	500 Ω	0.3 V

- Notes:
1. Input waveform: PRR = 10 MHz, duty cycle 50%
 2. Waveform – A shows input conditions such that the output is "L" level when enable by the output control.
 3. Waveform – B shows input conditions such that the output is "H" level when enable by the output control.

Package Dimensions

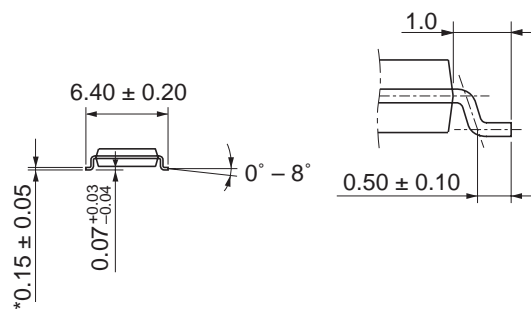
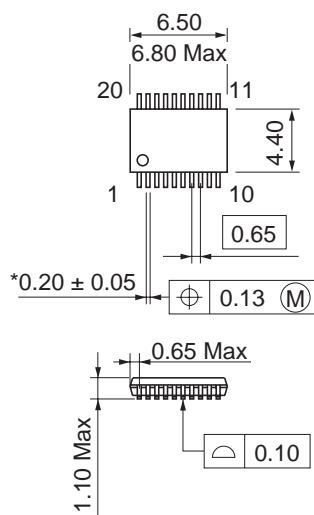
As of January, 2003
Unit: mm



*Ni/Pd/Au plating

Package Code	FP-20DAV
JEDEC	—
JEITA	Conforms
Mass (reference value)	0.31 g

As of January, 2003
Unit: mm



*Ni/Pd/Au plating

Package Code	TTP-20DAV
JEDEC	—
JEITA	—
Mass (reference value)	0.07 g

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